

isc N-Channel MOSFET Transistor

STF45N65M5

• FEATURES

- With TO-220F packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

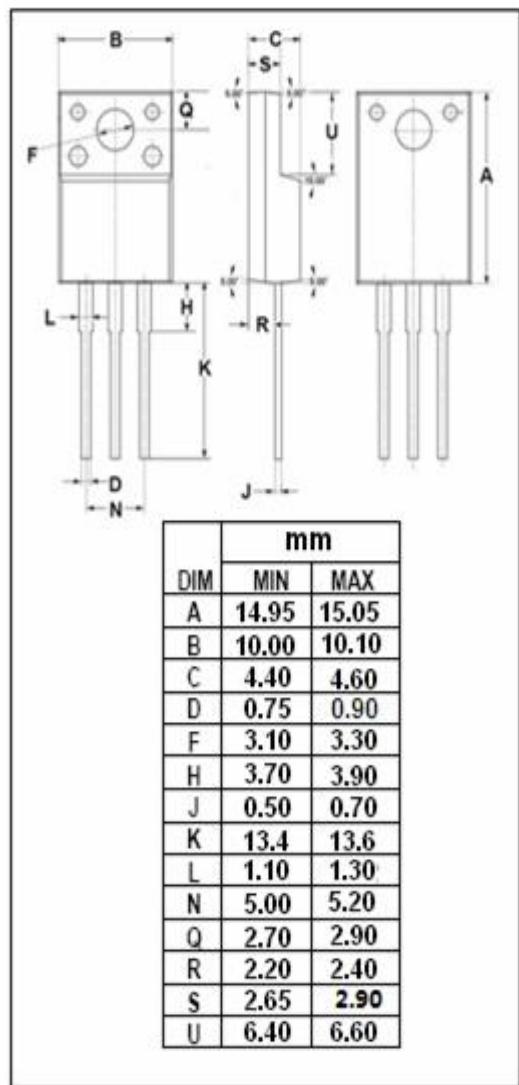
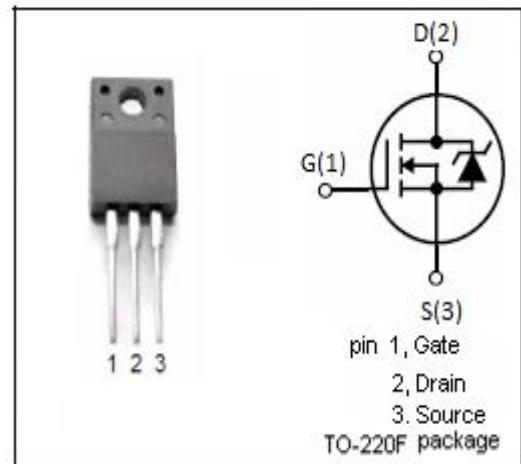
- Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage	650	V
V_{GSS}	Gate-Source Voltage	± 25	V
I_D	Drain Current-Continuous @ $T_c=25^\circ\text{C}$ $T_c=100^\circ\text{C}$	35 22	A
I_{DM}	Drain Current-Single Pulsed	140	A
P_D	Total Dissipation	40	W
T_j	Operating Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55~150	$^\circ\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(ch-c)}$	Channel-to-case thermal resistance	3.13	$^\circ\text{C}/\text{W}$
$R_{th(ch-a)}$	Channel-to-ambient thermal resistance	62.5	$^\circ\text{C}/\text{W}$



isc N-Channel MOSFET Transistor**STF45N65M5****ELECTRICAL CHARACTERISTICS** $T_c=25^\circ\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}; \text{I}_D= 1.0\text{mA}$	650			V
$\text{V}_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}; \text{I}_D=0.25\text{mA}$	3.0		5.0	V
$\text{R}_{\text{DS}(\text{on})}$	Drain-Source On-Resistance	$\text{V}_{\text{GS}}= 10\text{V}; \text{I}_D=17.5\text{A}$		67	78	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$\text{V}_{\text{GS}}=\pm 25\text{V}; \text{V}_{\text{DS}}= 0\text{V}$			± 0.1	μA
I_{DSS}	Drain-Source Leakage Current	$\text{V}_{\text{DS}}= 650\text{V}; \text{V}_{\text{GS}}= 0\text{V}; \text{Tc}=25^\circ\text{C}$ $\text{V}_{\text{DS}}= 650\text{V}; \text{V}_{\text{GS}}= 0\text{V}; \text{Tc}=125^\circ\text{C}$			1 100	μA
V_{SDF}	Diode forward voltage	$\text{I}_{\text{SD}}=35\text{A}, \text{V}_{\text{GS}} = 0 \text{ V}$			1.5	V